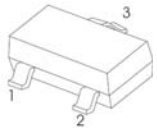
Brückewell

BSS138

N-Channel 50-V(D-S) MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$MAX	I_D
50 V	3.5Ω@10V	220mA
	6Ω@4.5V	

SOT-23



1. GATE
2. SOURCE
3. DRAIN

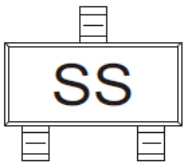
FEATURE

- High density cell design for extremely low $R_{DS(on)}$
- Rugged and Relaible

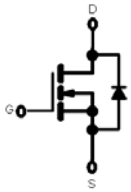
APPLICATION

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers;Display, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

MARKING



Equivalent Circuit



Maximum ratings (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	50	V
Continuous Gate-Source Voltage	V_{GSS}	±20	
Continuous Drain Current	I_D	0.22	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	℃/W
Operating Temperature	T_j	150	℃
Storage Temperature	T_{stg}	-55 ~+150	

MOSFET ELECTRICAL CHARACTERISTICS

BSS138

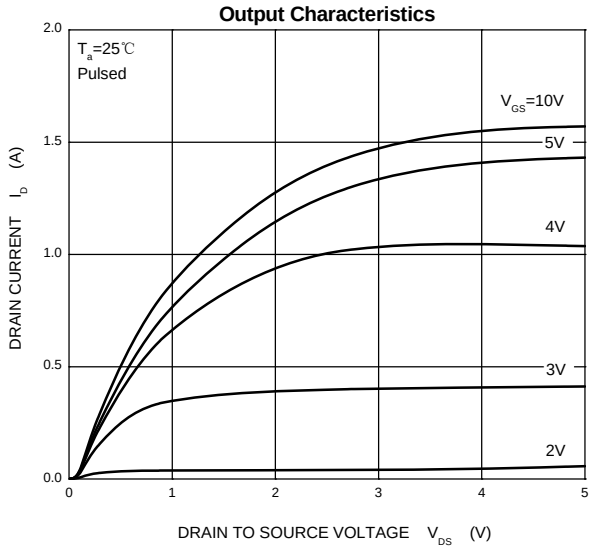
T_a=25℃ unless otherwise specified

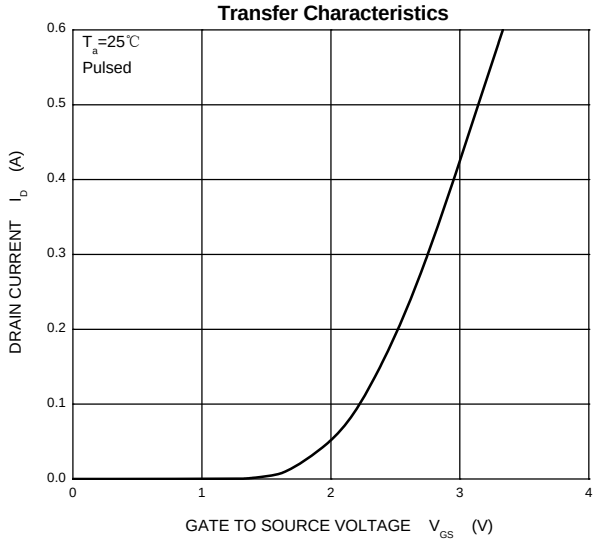
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =250μA	50			V
Gate-body leakage	I_{GSS}	V_{DS} =0V, V_{GS} =±20V			±100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} =50V, V_{GS} =0V			0.5	μA
		V_{DS} =30V, V_{GS} =0V			100	nA
On characteristics						
Gate-threshold voltage (note 1)	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =1mA	0.80		1.50	V
Static drain-source on-resistance (note 1)	$R_{DS(on)}$	V_{GS} =10V, I_D =0.22A			3.50	Ω
		V_{GS} =4.5V, I_D =0.22A			6	
Forward transconductance (note 1)	g_{FS}	V_{DS} =10V, I_D =0.22A	0.12			S
Dynamic characteristics (note 2)						
Input capacitance	C_{iss}	V_{DS} =25V,V_{GS} =0V, f=1MHz		27		pF
Output capacitance	C_{oss}			13		
Reverse transfer capacitance	C_{rss}			6		
Switching characteristics						
Turn-on delay time (note 1,2)	$t_{d(on)}$	V_{DD}=30V, V_{DS}=10V, I_D =0.29A,R_{GEN}=6Ω			5	ns
Rise time (note 1,2)	t_r				18	
Turn-off delay time (note 1,2)	$t_{d(off)}$				36	
Fall time (note 1,2)	t_f				14	
Drain-source body diode characteristics						
Body diode forward voltage (note 1)	V_{SD}	I_S=0.44A, V_{GS} = 0V			1.4	V

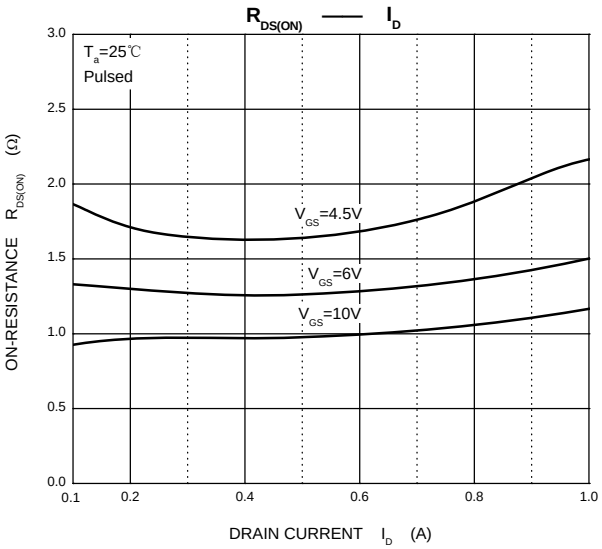
Notes:

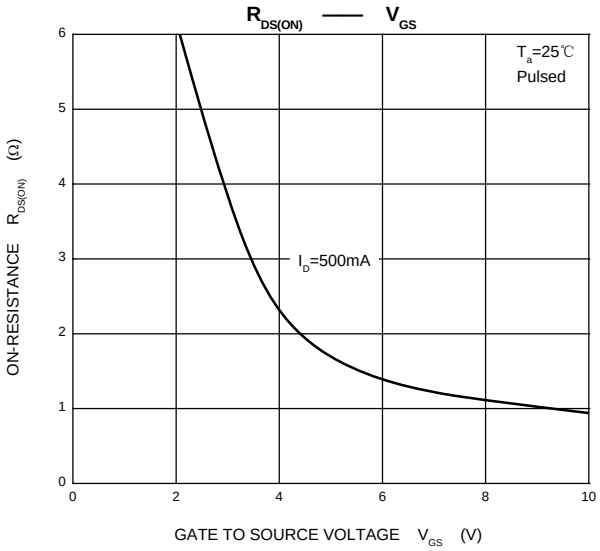
1. Pulse Test ; Pulse Width ≤300μs, Duty Cycle ≤2%.
2. These parameters have no way to verify.

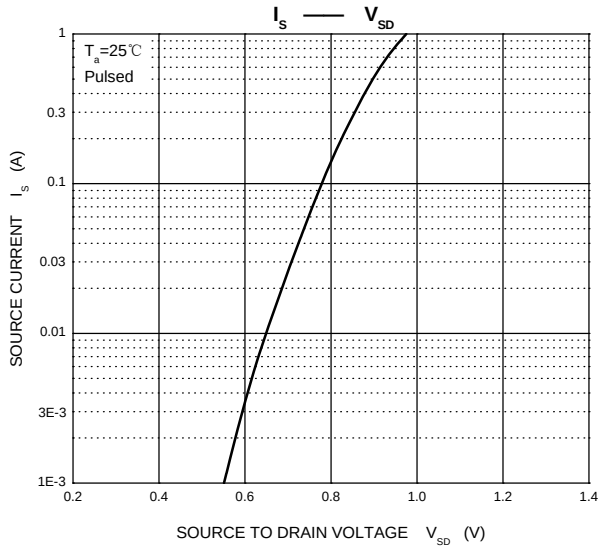
Typical Characteristics



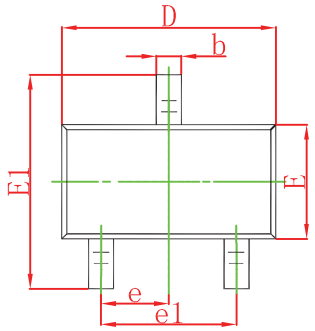


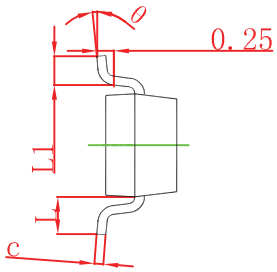


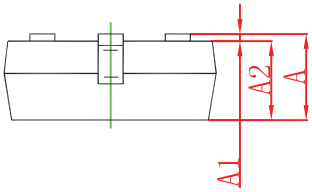




SOT-23 Package Outline Dimensions

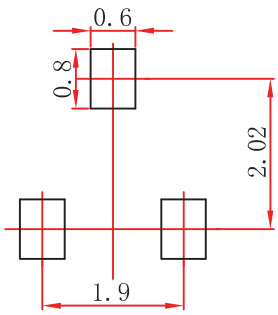






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	6°

SOT-23 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.